

Single Phase Half Controlled Bridges with freewheeling diode

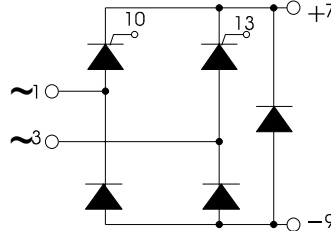
PSCH 75

$I_{TAVM} = 74 \text{ A}$
 $V_{RRM} = 400-1600 \text{ V}$

Preliminary Data Sheet

V_{RSM} V_{DSM}	V_{RRM} V_{DRM}	Type
500	400	PSCH 75/04
900	800	PSCH 75/08
1300	1200	PSCH 75/12
1500	1400	PSCH 75/14
*1700	*1600	PSCH 75/16

* Delivery on request



Symbol	Test Conditions	Maximum Ratings
I_{TAVM}	$T_C = 85^\circ\text{C}$	per module 74 A
I_{FSM}, I_{TSM}	$T_{VJ} = 45^\circ\text{C}$	$t = 10 \text{ ms}$ (50 Hz), sine 1150 A
	$V_R = 0$	$t = 8.3 \text{ ms}$ (60 Hz), sine 1230 A
	$T_{VJ} = T_{VJM}$	$t = 10 \text{ ms}$ (50 Hz), sine 1000 A
	$V_R = 0$	$t = 8.3 \text{ ms}$ (60 Hz), sine 1070 A
$\int i^2 dt$	$T_{VJ} = 45^\circ\text{C}$	$t = 10 \text{ ms}$ (50 Hz), sine 6600 $\text{A}^2 \text{ s}$
	$V_R = 0$	$t = 8.3 \text{ ms}$ (60 Hz), sine 6280 $\text{A}^2 \text{ s}$
	$T_{VJ} = T_{VJM}$	$t = 10 \text{ ms}$ (50 Hz), sine 5000 $\text{A}^2 \text{ s}$
	$V_R = 0$	$t = 8.3 \text{ ms}$ (60 Hz), sine 4750 $\text{A}^2 \text{ s}$
$(di/dt)_{cr}$	$T_{VJ} = T_{VJM}$	repetitive, $I_T = 150 \text{ A}$ 100 $\text{A}/\mu\text{s}$
	$f = 50\text{Hz}, t_p = 200\mu\text{s}$ $V_D = 2/3 V_{DRM}$ $I_G = 0.3 \text{ A}$ $di_G/dt = 0.3 \text{ A}/\mu\text{s}$	non repetitive, $I_T = I_{TAVM}$ 500 $\text{A}/\mu\text{s}$
$(dv/dt)_{cr}$	$T_{VJ} = T_{VJM}$ $R_{GK} = \infty$, method 1 (linear voltage rise)	$V_{DR} = 2/3 V_{DRM}$ 1000 $\text{V}/\mu\text{s}$
P_{GM}	$T_{VJ} = T_{VJM}$	$t_p = 30\mu\text{s}$ 10 W
	$I_T = I_{TAVM}$	$t_p = 300\mu\text{s}$ 5 W
P_{GAVM}		0.5 W
V_{RGM}		10 V
T_{VJ}		-40 ... + 125 $^\circ\text{C}$
T_{VJM}		125 $^\circ\text{C}$
T_{stg}		-40 ... + 125 $^\circ\text{C}$
V_{ISOL}	50/60 HZ, RMS	$t = 1 \text{ min}$ 2500 V ~
	$I_{ISOL} \leq 1 \text{ mA}$	$t = 1 \text{ s}$ 3000 V ~
M_d	Mounting torque	(M5) 5 Nm
	Terminal connection torque	(M3) 1.5 Nm
		(M5) 5 Nm
Weight	typ.	220 g

Features

- Package with screw terminals
- Isolation voltage 3000 V~
- Planar glasspassivated chips
- Low forward voltage drop
- UL registered, E 148688

Applications

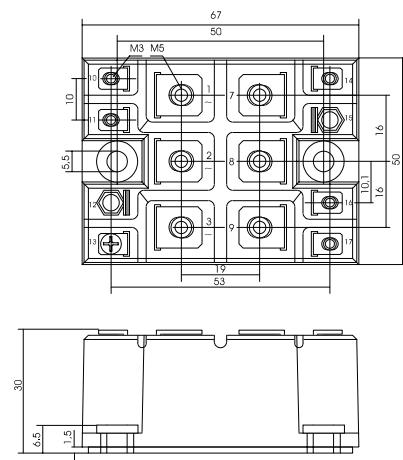
- Heat and temperature control for industrial furnaces and chemical processes
- Lighting control
- Motor control
- Power converter

Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling capability
- High power density

Package, style and outline

Dimensions in mm (1mm = 0.0394")



Symbol	Test Conditions	Characteristic Value	
I_D, I_R	$T_{VJ} = T_{VJM}, V_R = V_{RRM}, V_D = V_{DRM}$	\leq	5 mA
V_T	$I_T = 150A, T_{VJ} = 25^\circ C$	\leq	1.57 V
V_{TO}	For power-loss calculations only ($T_{VJ} = T_{VJM}$)		0.85 V
r_T			5,33 mΩ
V_{GT}	$V_D = 6V$	$T_{VJ} = 25^\circ C$	\leq 1.0 V
		$T_{VJ} = -40^\circ C$	\leq 1.6 V
I_{GT}	$V_D = 6V$	$T_{VJ} = 25^\circ C$	\leq 100 mA
		$T_{VJ} = -40^\circ C$	\leq 150 mA
V_{GD}	$T_{VJ} = T_{VJM}, V_D = 2/3 V_{DRM}$	\leq	0.2 V
I_{GD}	$T_{VJ} = T_{VJM}, V_D = 2/3 V_{DRM}$	\leq	5 mA
I_L	$T_{VJ} = 25^\circ C, t_p = 10\mu s$	\leq	200 mA
	$I_G = 0.3A, di_G/dt = 0.3A/\mu s$		
I_H	$T_{VJ} = 25^\circ C, V_D = 6V, R_{GK} = \infty$	\leq	150 mA
t_{gd}	$T_{VJ} = 25^\circ C, V_D = 1/2 V_{DRM}$	\leq	2 μs
	$I_G = 0.3A, di_G/dt = 0.3A/\mu s$		
t_q	$T_{VJ} = T_{VJM}, I_T = 20A, t_p = 200\mu s, V_R = 100V$		150 μs
	$-di/dt = 10A/\mu s, dv/dt = 15V/\mu s, V_D = 2/3 V_{DRM}$		
R_{thJC}	per thyristor; sine 180°el		0.66 K/W
	per module		0.132 K/W
R_{thJK}	per thyristor; sine 180° el		0.93 K/W
	per module		0.186 K/W
d_s	Creeping distance on surface		8.0 mm
d_A	Creeping distance in air		4.5 mm
a	Max. allowable acceleration		50 m/s ²

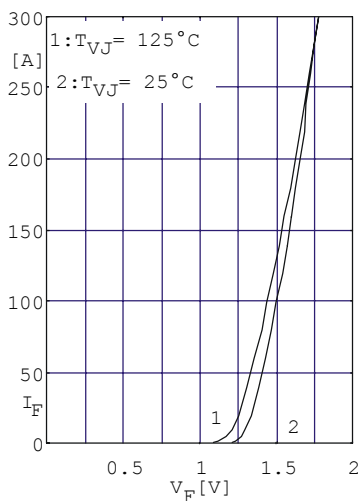


Fig. 1 Forward current vs. voltage drop per diode or thyristor

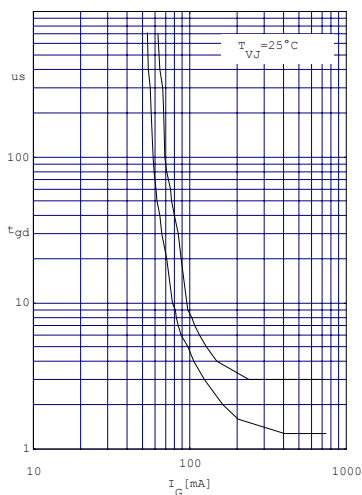


Fig. 2 Gate trigger delay time

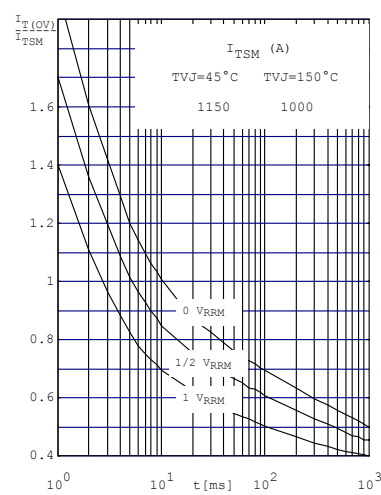


Fig. 3 Surge overload current per diode (or thyristor) I_{FSM} , I_{TSM} : Crest value t: duration

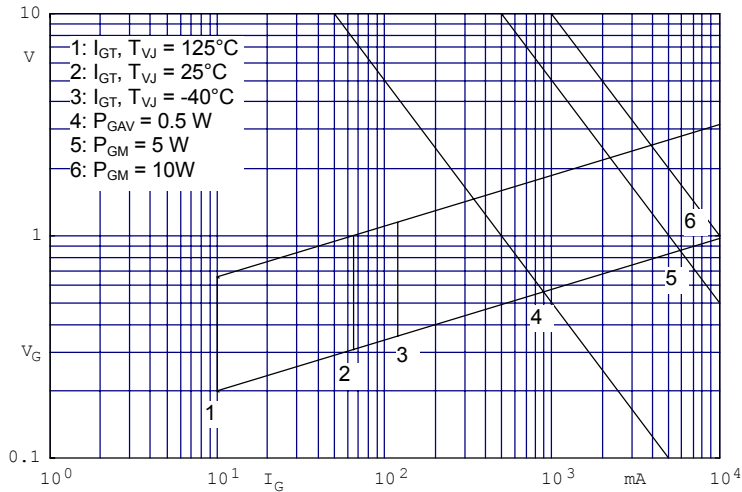


Fig.4 Gate trigger characteristic

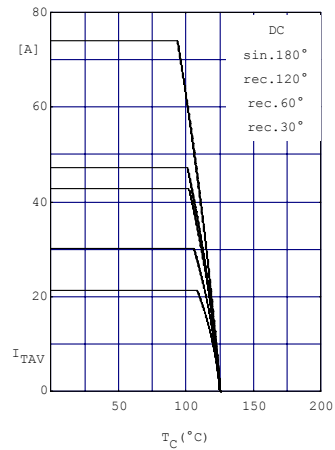


Fig.5 Maximum forward current at case temperature

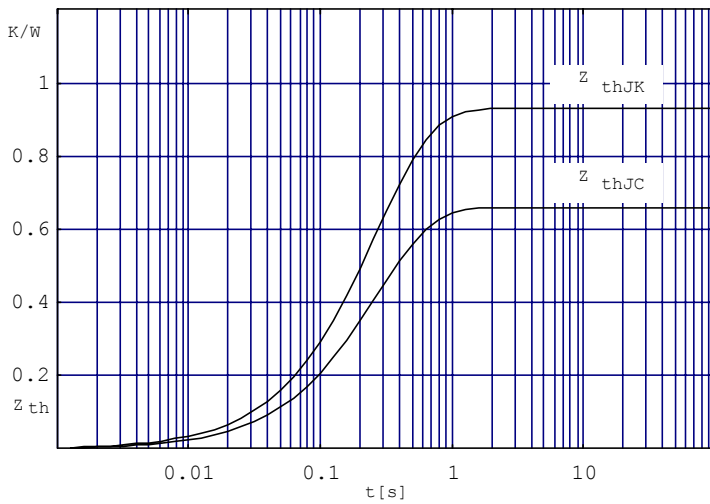


Fig.6 Transient thermal impedance per thyristor or diode (calculated)

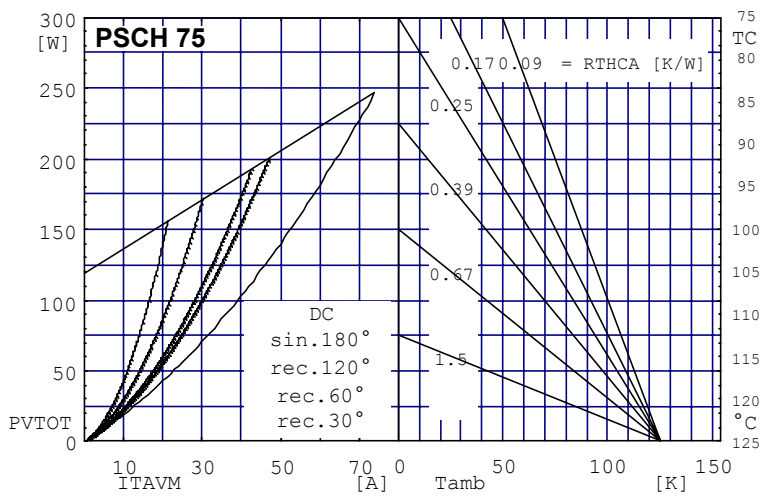


Fig. 7 Power dissipation vs. direct output current and ambient temperature